

PATENT APPLICATION

Applicant: Hyeong-Jun KIM Serial No. 10/636,027
Filing Date: August 6, 2003 Group: 2822
Title: MAGNETORESISTIVE MEMORY DEVICE AND METHOD FOR FABRICATING THE SAME

INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)U.S. PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
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FOREIGN PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
MP	_____	11-238377	Aug. 31, 99	Japan	Clarence, et al.
MP	_____	2001-0100862	Nov. 14, 01	Korea	_____

OTHER DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.</u>
MP	_____	English Language of Abstract for Korean Patent Publication No. 11-238377, August 1999
MP	_____	English Language of Abstract from PCT application for Korean Patent Publication No. 2001-0100862, November 2001

Examiner: 

Date Considered: 12/04